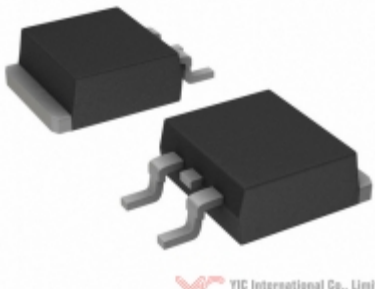



	<h2 style="color: red;">FQB33N10LTM</h2>
	<b>Hersteller-Teilenummer:</b> FQB33N10LTM
	<b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor
	<b>Teil der Beschreibung:</b> MOSFET N-CH 100V 33A D2PAK
	<b>Datenblätter:</b>  <a href="#">FQB33N10LTM.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 32561 pcs Stock Available.
<b>Liefern von:</b> Hong Kong	
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQB33N10LTM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 33A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	32561 pcs Stock
Hersteller Standard Vorlaufzeit	20 Weeks
detaillierte Beschreibung	N-Channel 100V 33A (Tc) 3.75W (Ta), 127W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 127W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	33A (Tc)
Rds On (Max) @ Id, Vgs	52 mOhm @ 16.5A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1630pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V, 10V
Vgs (Max)	±20V
Verpackung	Original-Reel®
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FQB33N10LTMDKR



FQB33N10LTM ist neu im Original, Suche FQB33N10LTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB33N10LTM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB33N10LTM: Info@Y-IC.com

Sie können auch interessiert sein:

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<b>FQB32N30</b> FAIRCHILD FQB32N30 FAIRCHILD	<b>FQB32N20CTM</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 28A D2PAK	<b>FQB34N20L</b> FAIRCHI FQB34N20L FAIRCHI	<b>FQB34N20</b> F FQB34N20 F
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<b>FQB33N10TM</b> Fairchild/ON Semiconductor MOSFET N-CH 100V 33A D2PAK	<b>FQB33N25</b> Fairchild/ON Semiconductor FQB33N25 FAIRCHILD	<b>FQB33N10L</b> F FQB33N10L F	<b>FQB33N10</b> F FQB33N10 F

heiße Teile

Mehr

 FQB2N50C	 FQB2N60TM	 FQB2N60TM	 FQB2N80TM	 FQB2N80TM
 FQB2NA90TM	 FQB2NA90TM	 FQB2P25TM	 FQB2P25TM	 FQB30N06
 FQB30N06L	 FQB30N06LTM	 FQB30N06LTM	 FQB30N06TM	 FQB30N06TM
 FQB32N12V2	 FQB32N12V2TM	 FQB32N12V2TM	 FQB32N20	 FQB32N20C
 FQB32N20CTM	 FQB32N20CTM	 FQB32N30	 FQB33N10	 FQB33N10L
 FQB33N10LTM	 FQB33N10TM	 FQB33N10TM	 FQB34N20	 FQB34N20L
 FQB34N20LTM	 FQB34N20LTM	 FQB34N20TM	 FQB34N20TM_AM002	 FQB34P10
 FQB34P10TM	 FQB34P10TM	 FQB34P10TM_F085	 FQB3N25TM	 FQB3N25TM
 FQB3N30TM	 FQB3N30TM	 FQB3N40TM	 FQB3N40TM	 FQB3N60C
 FQB3N80TM	 FQB3N80TM	 FQB3N90TM	 FQB3N90TM	 FQB3P20TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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